Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic and metal
Overall Length:
23.0 millimeters
Overall Height:
0.9 millimeters
End Application:
Apn232, r.F. Assembly
Mounting Method:
Terminal
Features Provided:
Burn in and hermetically sealed case Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
22.0 breakdown voltage, dc
Capacitance Rating In Picofarads:
Between 1.8 and 2.2
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Terminal Type And Quantity:
2 pin
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0